



Bipolar PNP Bare Die – BTP6038

Part Description

The BTP6038 is a silicon BJT transistor available in bare die form and well suited for use in applications

Key Parameters:

- VCBO = -50V
- VCEO = -50V
- VEBO = -5V
- hFE = 70-240 @ VCE = -2V, IC = -0.5A
- VCE(Sat) = -0.5V @ IC = -1A, IB = -50mA
- fT = 110 MHz @ VCE = -2V, IE = 0A
- COBO = 15pF @ VCB = -10V

Features

Low VCE(sat). Designed to provide performance equivalent to TOSHIBA 2SA1213 or ROHM 2SA1794

Die Size (Unawn)

700µm X 700µm, 28 Mils X 28 Mils

This is a shortform datasheet only

For the full datasheet

Please contact sales@siliconsupplies.com

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